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## Sommario/riassunto

A unique, state-of-the-art guide to wireless integrated circuit design. With wireless technology rapidly exploding, there is a growing need for circuit design information specific to wireless applications. Presenting a single-source guidebook to this dynamic area, industry expert Ulrich Rohde and writer David Newkirk provide researchers and engineers with a complete set of modeling, design, and implementation tools for tackling even the newest IC technologies. They emphasize practical design solutions for high-performance devices and circuitry, incorporating ample examples of novel and

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